

isc Silicon NPN Power Transistors

DESCRIPTION

- Low Collector Saturation Voltage
 : V_{CE(sat)}= 0.4V(Max)@ I_C= 3A
- · Large Current Capacity
- Complement to Type 2SB919
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

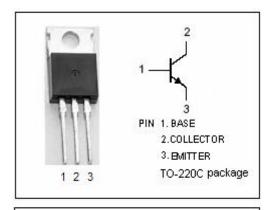
APPLICATIONS

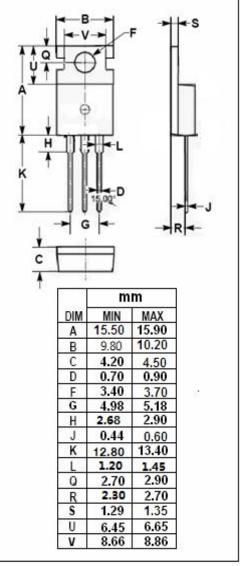


 Large current switching of relay drivers, high-speed inverters, converters.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{СВО}	Collector-Base Voltage	60	V
Vceo	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	6	V
lc	Collector Current-Continuous	8	Α
I _{CP}	Collector Current-Pulse	15	Α
P _C	Collector Power Dissipation @ T _a =25℃	1.75	W
	Collector Power Dissipation @ T _C =25℃	30	VV
TJ	Junction Temperature 150		$^{\circ}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$







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2SD1235

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I _C = 1mA; R _{BE} = ∞	30			V	
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA; I _E = 0	60			V	
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	6			V	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 3A; I _B = 0.15A			0.4	V	
I _{CBO}	Collector Cutoff Current	V _{CB} = 40V; I _E = 0			100	μА	
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C = 0			100	μА	
h _{FE-1}	DC Current Gain	I _C = 1A; V _{CE} = 2V	70		280		
h _{FE-2}	DC Current Gain	I _C = 4A; V _{CE} = 2V	30				
f⊤	Current-Gain—Bandwidth Product	Ic= 1A; VcE= 5V		120		MHz	
Switching times							
ton	Turn-on Time			0.1		μS	
t _{stg}	Storage Time	I _C = 4A; I _{B1} = I _{B2} = 0.2A R _L = 2.5 Ω; P _W =20 μ s; V _{CC} = 10V		0.5		μS	
t _f	Fall Time			0.03		μ \$	

♦ h_{FE-1} Classifications

Q	R	S
70-140	100-200	140-280

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